



桥式整流器 Bridge Rectifier

■特征 Features

- $I_o$  1A
- $V_{RRM}$  50V~1000V
- 玻璃钝化芯片  
Glass passivated chip
- 耐正向浪涌电流能力高  
High surge forward current capability

■用途 Applications

- 作一般电源单相桥式整流用  
General purpose 1 phase Bridge rectifier applications

■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	DB1						
				01	02	03	04	05	06	07
反向重复峰值电压 Repetitive Peak Reverse Voltage	$V_{RRM}$	V		50	100	200	400	600	800	1000
平均整流输出电流 Average Rectified Output Current	$I_o$	A	60Hz正弦波, 电阻负载, $T_a=25^\circ\text{C}$ 60Hz sine wave, R-load, $T_a=25^\circ\text{C}$	1						
正向(不重复)浪涌电流 Surge(Non-repetitive) Forward Current	$I_{FSM}$	A	60Hz正弦波, 一个周期, $T_j=25^\circ\text{C}$ 60Hz sine wave, 1 cycle, $T_j=25^\circ\text{C}$	30						
正向浪涌电流的平方对电流 浪涌持续时间的积分值 Current Squared Time	$I^2t$	A <sup>2</sup> S	1ms≤t<8.3ms $T_j=25^\circ\text{C}$ , 单个二极管 1ms≤t<8.3ms $T_j=25^\circ\text{C}$ , Rating of per diode	3.7						
存储温度 Storage Temperature	$T_{stg}$	°C		-55 ~ +150						
结温 Junction Temperature	$T_j$	°C		-55 ~ +150						

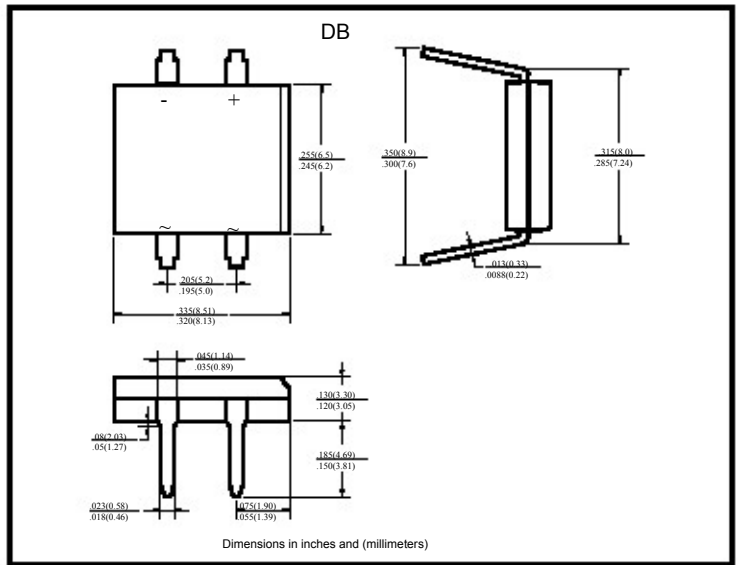
■电特性 (Ta=25°C 除非另有规定)

Electrical Characteristics (Ta=25°C Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Condition	最大值 Max
正向峰值电压 Peak Forward Voltage	$V_{FM}$	V	$I_{FM}=0.5A$ , 脉冲测试, 单个二极管的额定值 $I_{FM}=0.5A$ , Pulse measurement, Rating of per diode	1.05
反向峰值电流 Peak Reverse Current	$I_{RRM}$	μA	$V_{RM}=V_{RRM}$ , 脉冲测试, 单个二极管的额定值 $V_{RM}=V_{RRM}$ , Pulse measurement, Rating of per diode	10
热阻 Thermal Resistance	$R_{\theta J-A}$	°C/W	结和环境之间, 安装在玻璃-环氧基板上 Between junction and ambient, On glass-epoxi substrate	68
	$R_{\theta J-L}$		结和引线之间 Between junction and lead	15

■外形尺寸和印记

Outline Dimensions and Mark



■特性曲线（典型） Characteristics(Typical)

图1:  $I_o$ - $T_a$ 曲线  
FIG1: $I_o$ - $T_a$  Curve

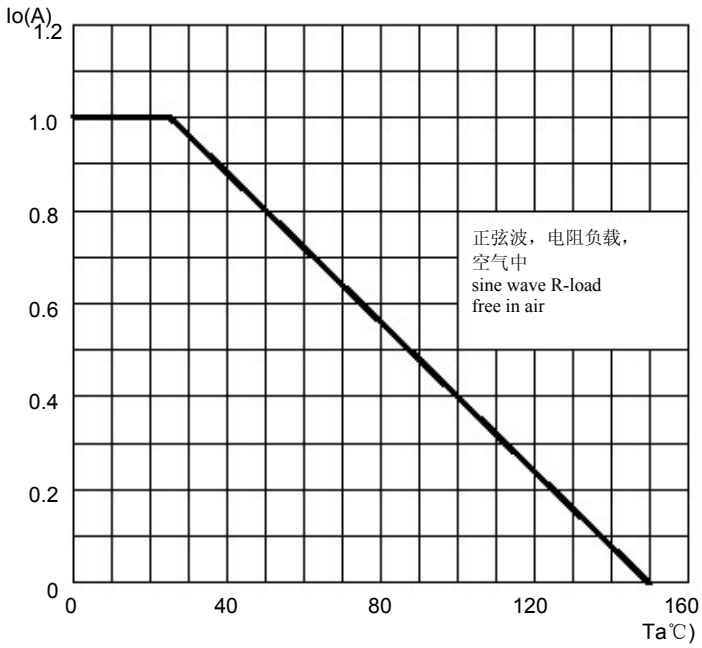


图2: 耐正向浪涌电流曲线  
FIG2: Surge Forward Current Capability

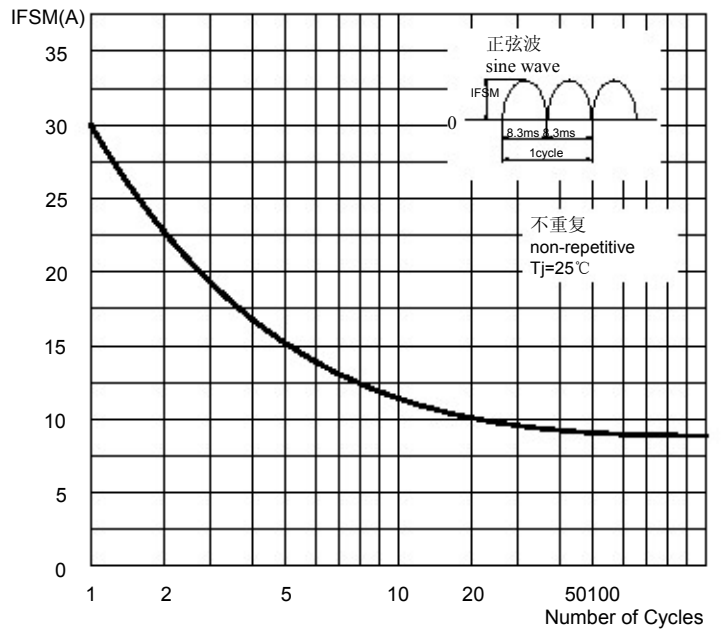


图3: 正向电压曲线  
FIG3: Forward Voltage

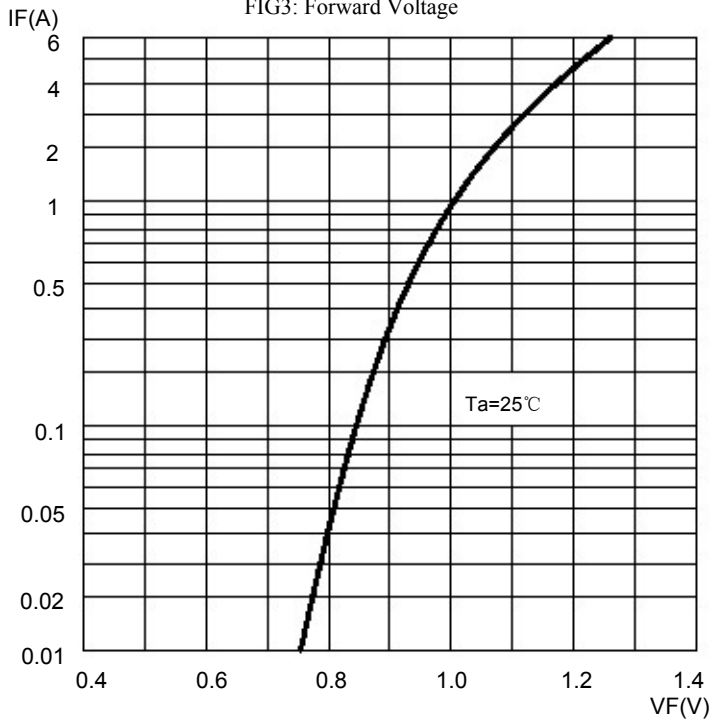


图4: 反向电流曲线  
FIG4: Typical Reverse Characteristics

